CD74HC4538-Q1 汽车类高速 CMOS 逻辑双通道可重触发精密单稳多谐振荡器

1 特性

- 符合汽车应用要求
- 符合汽车应用的可重触发/可复位功能要求
- 触发和复位传播延迟不受 R_X、C_X 的影响
- 从前沿或后沿触发
- 提供 Q 和 $\overline{Q}$ 缓冲输出
- 单独复位
- 宽范围的输出脉冲宽度
- A 和 $\overline{B}$ 输入端的施密特触发器输入
- 再触发时间与 C_X 无关
- 扇出（在温度范围内）
  - 标准输出 10 个 LSTTL 负载
  - 总线驱动器输出 15 个 LSTTL 负载
- 平衡的传播延迟及转换时间
- 与 LSTTL 逻辑 IC 相比，可显著降低功耗
- V_{CC} 电压 = 2V 至 6V
- 高抗噪性，N_{IL} 或 N_{IH} = V_{CC} 的 30%，V_{CC} = 5V

2 说明

CD74HC4538 是一款适用于固定电压时序应用的双路可重触发/可复位精密单稳多谐振荡器。

封装信息

器件型号	封装(1)	封装尺寸(2)	本体尺寸
CD74HC4538-Q1	D（SOIC，16）	9.9mm × 6mm	9.9mm x 3.90mm
	PW（TSSOP，16）	5mm × 6.4mm	5.00mm x 4.40mm

(1) 如需了解更多信息，请参阅机械、封装和可订购信息。
(2) 封装尺寸（长 × 宽）为标称值，并包括引脚（如适用）。
(3) 本体尺寸（长 × 宽）为标称值，不包括引脚。

Table of Contents

3 Pin Configuration and Functions

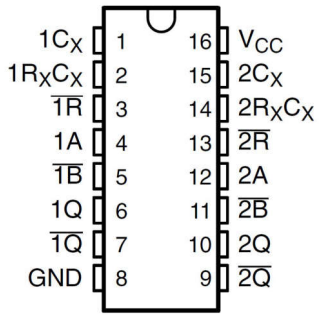


图 3-1. D or PW Package; 16-Pin SOIC or TSSOP (Top View)

表 3-1. Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
$1C_X$	1	—	Connects to external capacitor
$1R_XC_X$	2	—	Connects to external capacitor and resistor
1 $\overline{1R}$	3	—	Connects to external resistor
1A	4	I	Ch1 Rising edge input
1B	5	I	Ch1 Falling edge input
1Q	6	O	Ch1 Output
$\overline{1Q}$	7	O	Ch1 Inverted Output
GND	8	—	Ground
$\overline{2Q}$	9	O	Ch2 Inverted Output
2Q	10	O	Ch2 Output
$\overline{2B}$	11	I	Ch2 Falling edge input
2A	12	I	Ch2 Rising edge input
2R	13	—	Connects to external resistor
$2R_XC_X$	14	—	Connects to external capacitor and resistor
$2C_X$	15	—	Connects to external capacitor
V_{CC}	16	—	Power Pin

4 Specifications

4.1 Absolute Maximum Ratings

over operating free-air temperature (unless otherwise noted)(1)

			MIN	MAX	UNIT
V_{CC}	Supply voltage(2)		–0.5	7	V
I_{IK}	Input clamp current	(V_I < −0.5V or V_I > V_{CC} + 0.5V)		±20	mA
I_{OK}	Output clamp current	(V_O < −0.5V or V_O > V_{CC} + 0.5V)		±20	mA
I_O	Switch current per output pin	(V_O > −0.5V or V_O < V_{CC} + 0.5V)		±25	mA
	Continuous current through V_{CC} or GND			±50	mA
T_J	Maximum junction temperature			150	°C
T_{stg}	Storage temperature range		–65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltages are referenced to GND, unless otherwise specified.

4.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per AEC Q100-002(1)	±1500	V
		Charged device model (CDM), per AEC Q100-011	±250	

(1) AEC Q100-002 indicates that HBM stressing must be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

4.3 Recommended Operating Conditions

over operating free-air temperature (unless otherwise noted)

				MIN	MAX	UNIT
V_{CC}	Supply voltage			2	6	V
V_{IH}	High-level input voltage		V_{CC} = 2V	1.5		V
			V_{CC} = 4.5V	3.15		
			V_{CC} = 6V	4.2		
V_{IL}	Low-level input voltage		V_{CC} = 2V		0.5	V
			V_{CC} = 4.5V		1.35	
			V_{CC} = 6V		1.8	
V_I	Input voltage			0	V_{CC}	V
V_O	Output voltage			0	V_{CC}	V
t_t	Input transition (rise and fall) time	Reset input	V_{CC} = 2V	0	1000	ns
			V_{CC} = 4.5V	0	500	
			V_{CC} = 6V	0	400	
		Trigger inputs A or $\overline{B}$	V_{CC} = 2V	0	Unlimited	
			V_{CC} = 4.5V	0	Unlimited	
			V_{CC} = 6V	0	Unlimited	
R_X	External timing resistor(1)			5		kΩ
C_X	External timing capacitor(1)			0		F
T_A	Operating free-air temperature			–40	125	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

4.4 Thermal Information

THERMAL METRIC[1]		CD74HC4538-Q1		UNIT
		D	PW	
		16 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	73	108	°C/W

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report (SPRA953).

4.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		I_OmA	V_{CC}	T_A = 25°C		T_A = −40°C TO 85°C		T_A = −40°C TO 125°C		UNIT
					MIN	MAX	MIN	MAX	MIN	MAX	
V_{OH}	V_I = V_{IH} or V_{IL}	CMOS loads	−0.02	2 V	1.9		1.9		1.9		V
				4.5 V	4.4		4.4		4.4		
				6 V	5.9		5.9		5.9		
		TTL loads	− 4	4.5 V	3.98		3.84		3.7		
			−5.2	6 V	5.48		5.34		5.2		
V_{OL}	V_I = V_{IH} or V_{IL}	CMOS loads	0.02	2 V		0.1		0.1		0.1	V
				4.5 V		0.1		0.1		0.1	
				6 V		0.1		0.1		0.1	
		TTL loads	4	4.5 V		0.26		0.33		0.4	
			5.2	6 V		0.26		0.33		0.4	
I_I	V_I = V_{CC} or GND	A, $\overline{B}$, R		6 V		±1		±1		±1	µA
		R_XC_X [1]		6 V		±0.05		±0.05		±0.05	
I_{CC}	V_I = V_{CC} or GND	Quiescent	0	6 V		8		80		160	µA
		Active, Q = high, Pins 2 and 14 at V_{CC}/4	0	6 V		0.6		0.8		1	mA
C_{IN}	C_L = 50 pF					10		10		10	pF

(1) When testing I_{IL}, the Q output must be high. If Q is low (device not triggered), the pullup P device is ON and the low-resistance path from V_{DD} to the test pin causes a current far exceeding the specification.

4.6 Timing Requirements

over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER		V_{CC}	T_A = 25°C			T_A = −40°C TO 85°C		T_A = −40°C TO 125°C		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_w	Input pulse width	2 V	80			100		120		ns
		4.5 V	16			20		24		
		6 V	14			17		20		
t_{su}	Reset setup time	2 V	5			5		5		ns
		4.5 V	5			5		5		
		6 V	5			5		5		
t_{rr}	Retrigger time	5 V		175						ns
	Output pulse-width match, same package			± 1						%

4.7 Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	V_{CC}	T_A = 25°C			T_A = –40°C TO 85°C		T_A = –40°C TO 125°C		UNIT
					MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{pd}	A, $\overline{B}$	Q or $\overline{Q}$	C_L = 50 pF	2 V			250		315		375	ns
				4.5 V			50		63		75	
				6 V			43		54		64	
			C_L = 15 pF	5 V		21						
	$\overline{R}$	Q or $\overline{Q}$	C_L = 50 pF	2 V			250		315		375	ns
				4.5 V			50		63		75	
				6 V			43		54		64	
			C_L = 15 pF	5 V		21						
t_t			C_L = 50 pF	2 V			75		95		110	ns
				4.5 V			15		19		22	
				6 V			13		16		19	
τ (1)			C_L = 50 pF	3 V	0.64		0.78	0.612	0.812	0.605	0.819	ms
				5 V	0.63		0.77	0.602	0.798	0.595	0.805	

(1) Output pulse width with R_X = 10 kΩ and C_X = 0.1 µF

4.8 Operating Characteristics

V_{CC} = 5 V, T_A = 25°C, input t_r, t_f = 6 ns, C_L = 15 pF

PARAMETER		TYP	UNIT
C_{pd}	Power dissipation capacitance	136	pF

备注

- C_{pd} is used to determine the dynamic power consumption, per one shot.
- $P_D = (C_{pd} + C_X) V_{CC} 2 f_I \Sigma (C_L V_{CC} 2 f_O)$
- f_I = input frequency
- f_O = output frequency
- C_L = output load capacitance
- C_X = external capacitance
- V_{CC} = supply voltage, assuming f_I I/ τ

4.9 Typical Characteristics

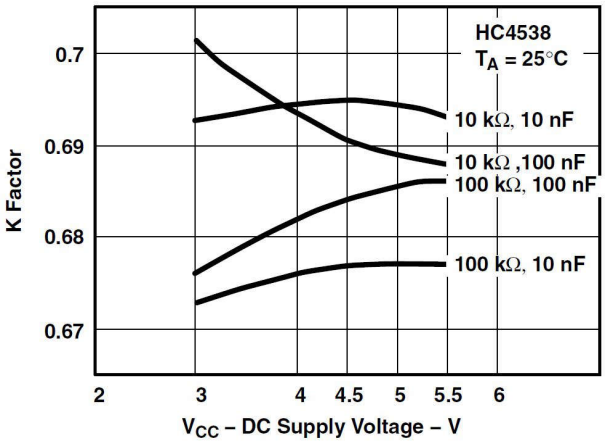


图 4-1. K Factor vs DC Supply Voltage

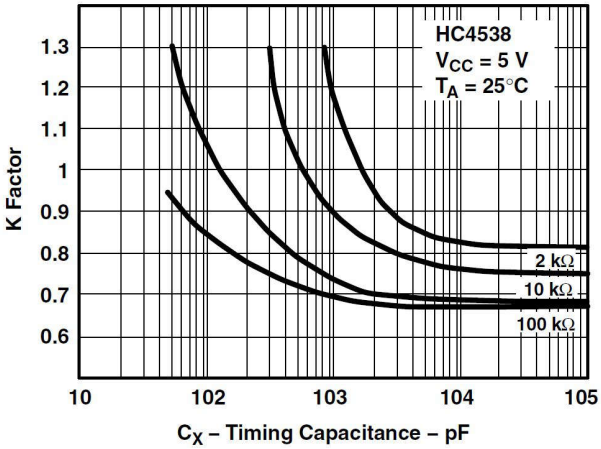


图 4-2. K Factor vs C_X

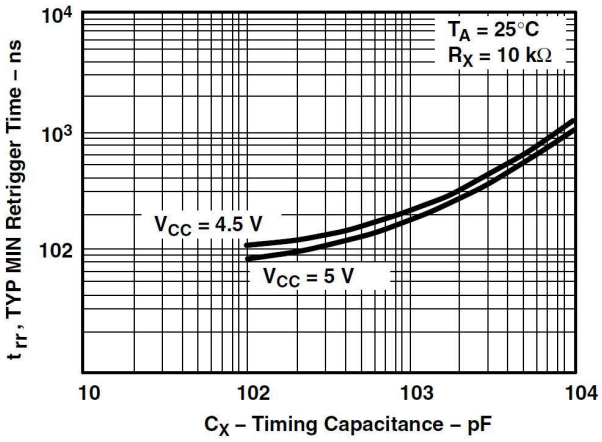


图 4-3. Minimum Retrigger Time vs Timing Capacitance

5 Parameter Measurement Information

Load Circuit and Voltage Waveforms

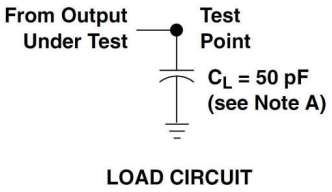


图 5-1. Load Circuit

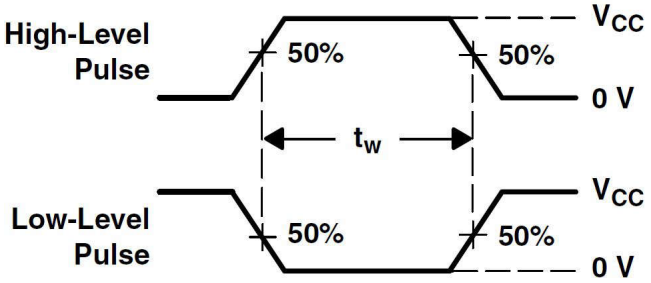


图 5-2. Voltage Waveforms Pulse Durations

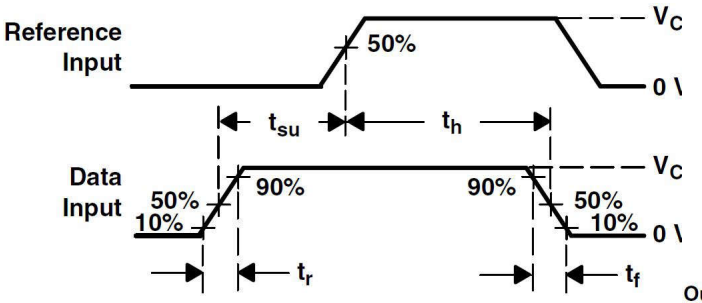


图 5-3. Voltage Waveforms Setup and Hold and Input Rise and Fall Times

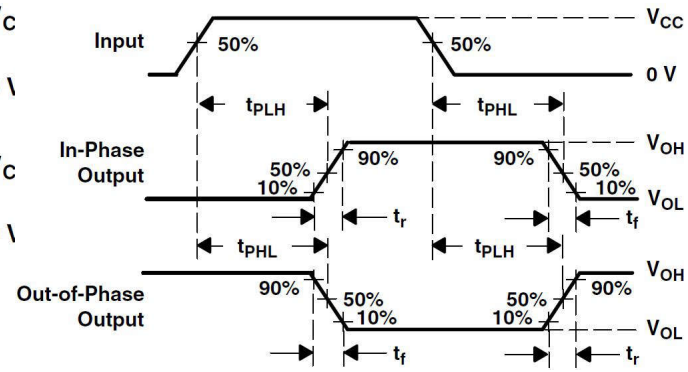


图 5-4. Voltage Waveforms Propagation Delay and Output Transition Times

备注

- C_L includes probe and test-fixture capacitance.
- Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR ⩽ 1 MHz, Z_O = 50 Ω, t_r = 6 ns, t_f = 6 ns.
- For clock inputs, f_{max} is measured when the input duty cycle is 50%.
- The outputs are measured one at a time, with one input transition per measurement.
- t_{PLH} and t_{PHL} are the same as t_{pd}.

6 Detailed Description

6.1 Overview

An external resistor (R_X) and external capacitor (C_X) control the timing and accuracy for the circuit. Adjustment of R_X and C_X provides a wide range of output pulse widths from the Q and $\overline{Q}$ terminals. The propagation delay from trigger input-to-output transition and the propagation delay from reset input-to-output transition are independent of R_X and C_X.

Leading-edge triggering (A) and trailing-edge triggering ($\overline{B}$) inputs are provided for triggering from either edge of the input pulse. An unused A input should be tied to GND and an unused $\overline{B}$ input should be tied to V_{CC}. On power up, the IC is reset. Unused resets and sections must be terminated. In normal operation, the circuit retriggers on the application of each new trigger pulse. To operate in the nontriggerable mode, $\overline{Q}$ is connected to $\overline{B}$ when leading-edge triggering (A) is used, or Q is connected to A when trailing-edge triggering ($\overline{B}$) is used. The period (τ) can be calculated from $\tau = (0.7) R_X, C_X$; R_{MIN} is 5 kΩ. C_{MIN} is 0 pF.

6.2 Functional Block Diagram

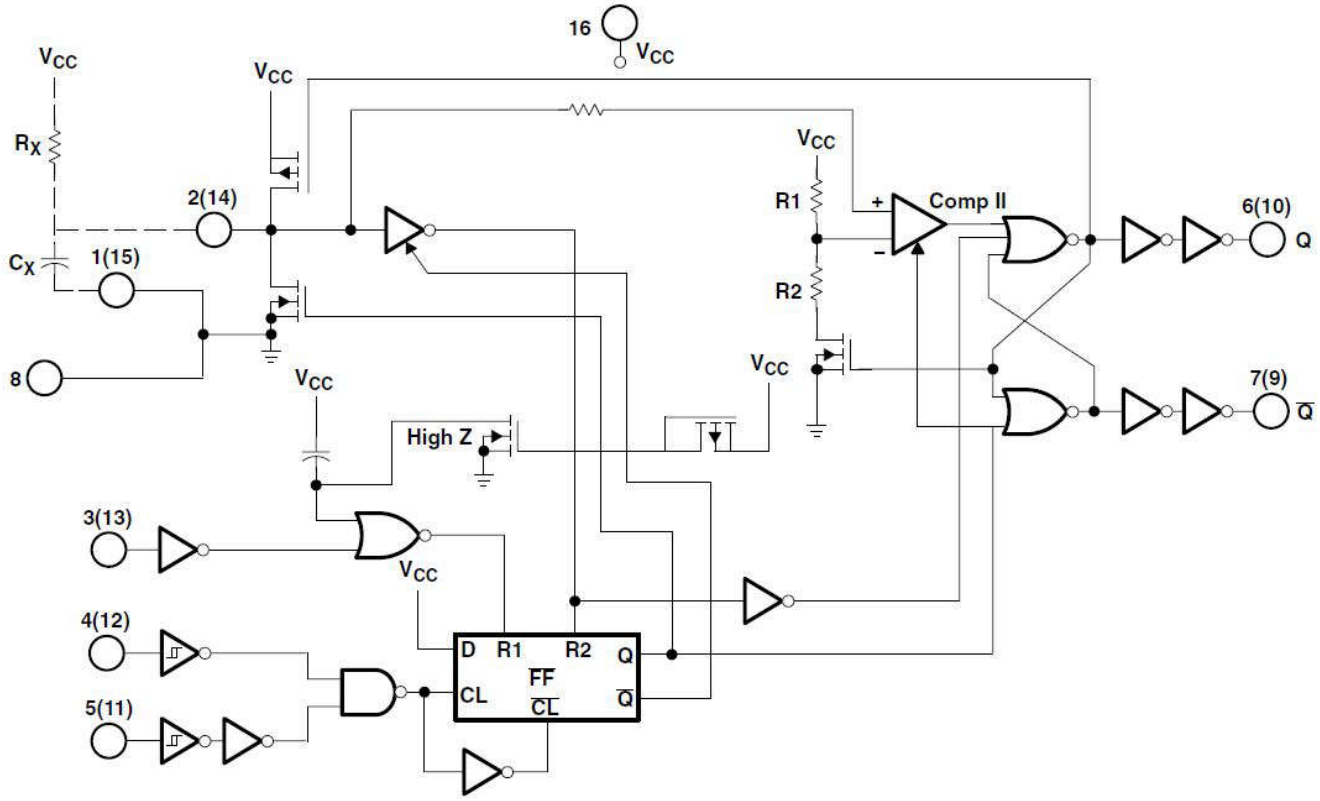


图 6-1. Logic Diagram (Positive Logic)

6.3 Device Functional Modes

表 6-1. Function Table

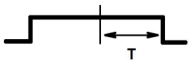
INPUTS			OUTPUTS	
$\overline{R}$	A	$\overline{B}$	Q	$\overline{Q}$
L	X	X	L	H
X	H	X	L	H
X	X	L	L	H
H	L	↓	⎍	⎎
H	↑	H	⎍	⎎

表 6-2. Functional Terminal Connections

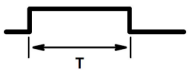
FUNCTION	V_{CC} TO TERMINAL NUMBER		GND TO TERMINAL NUMBER		INPUT PULSE TO TERMINAL NUMBER		OTHER CONNECTIONS	
	MONO(1)	MONO(2)	MONO(1)	MONO(2)	MONO(1)	MONO(2)	MONO(1)	MONO(2)
Leading-edge trigger/ retriggerable	3, 5	11, 13			4	12		
Leading-edge trigger/ nonretriggerable	3	13			4	12	5−7	11−9
Trailing-edge trigger/ retriggerable	3	13	4	12	5	11		
Trailing-edge trigger/ nonretriggerable	3	13			5	11	4−6	12−10

(1) A retriggerable one-shot multivibrator has an output pulse width that is extended one full time period (T) after application of the last trigger pulse.
(2) A nontriggerable one-shot multivibrator has a time period (T) referenced from the application of the first trigger pulse.

Input Pulse Train



Retriggerable Mode Pulse Width (A Mode)



Nonretriggerable Mode Pulse Width (A Mode)

7 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客 户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

7.1 Typical Application

Power-Down Mode

During a rapid power-down condition (as would occur with a power-supply short circuit with a poorly filtered power supply), the energy stored in C_X could discharge into pin 2 or pin 14. To avoid possible device damage in this mode when C_X is \u0001 0.5 µF, a protection diode with a 1-A rating or higher (1N5395 or equivalent) and a separate ground return for C_X should be provided. Rapid-Power-Down Protection Circuit

An alternate protection method is shown in Alternative Rapid-Power-Down Protection Circuit, where a 51-Ω current-limiting resistor is inserted in series with C_X . Note that a small pulse-duration decrease occurs, however, and R_X must be increased appropriately to obtain the originally desired pulse duration.

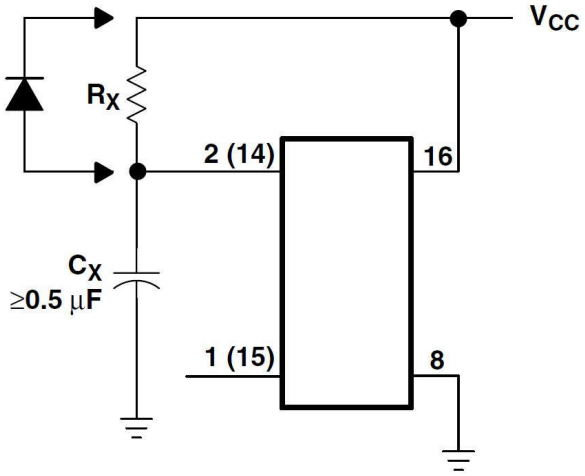


图 7-1. Rapid-Power-Down Protection Circuit

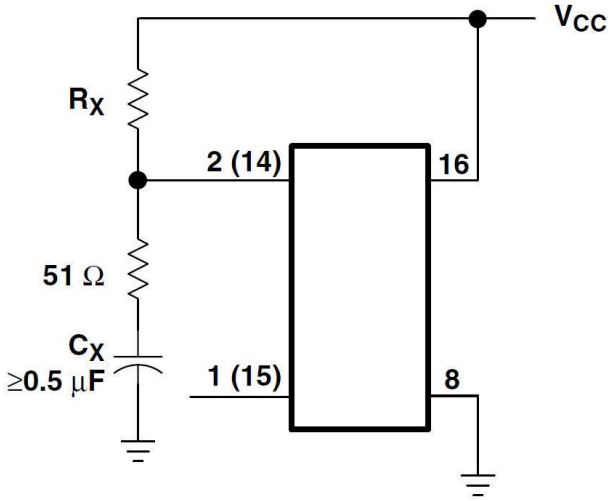


图 7-2. Alternative Rapid-Power-Down Protection Circuit

7.2 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1-µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. The 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in the following layout example.

7.3 Layout

7.3.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used,

or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC}, whichever makes more sense or is more convenient. It is acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the I/Os so they also cannot float when disabled.

8 Device and Documentation Support

8.1 Documentation Support (Analog)

8.1.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

表 8-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
CD74HC4538-Q1	Click here	Click here	Click here	Click here	Click here

8.2 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击*通知* 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

8.3 支持资源

TI E2E™ 中文支持论坛是工程师的重要参考资料，可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题，获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的使用条款。

8.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.
所有商标均为其各自所有者的财产。

8.5 静电放电警告

静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

8.6 术语表

TI 术语表　　本术语表列出并解释了术语、首字母缩略词和定义。

9 Revision History

Changes from Revision A (April 2008) to Revision B (August 2024)	Page
• 添加了*封装信息* 表、*引脚功能* 表、*ESD 等级* 表、*热性能信息* 表、*器件功能模式*、“应用和实施”部分、*器件和文档支持* 部分以及*机械、封装和可订购信息* 部分	1

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CD74HC4538QM96G4Q1	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HC4538M	Samples
CD74HC4538QPWRG4Q1	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HC4538M	Samples
CD74HC4538QPWRQ1	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HC4538M	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD74HC4538-Q1 :

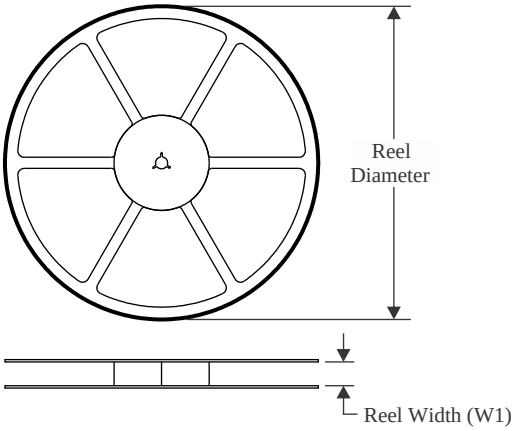
- Catalog : CD74HC4538
- Military : CD54HC4538

NOTE: Qualified Version Definitions:

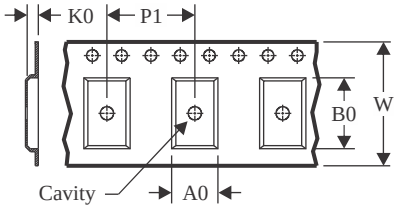
- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION

REEL DIMENSIONS

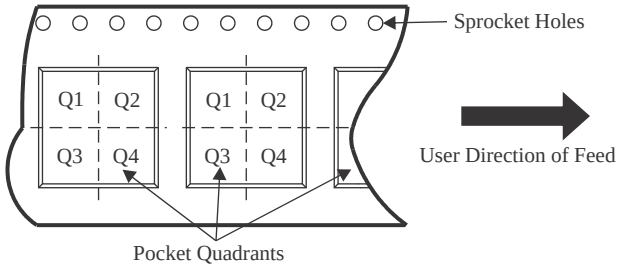


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

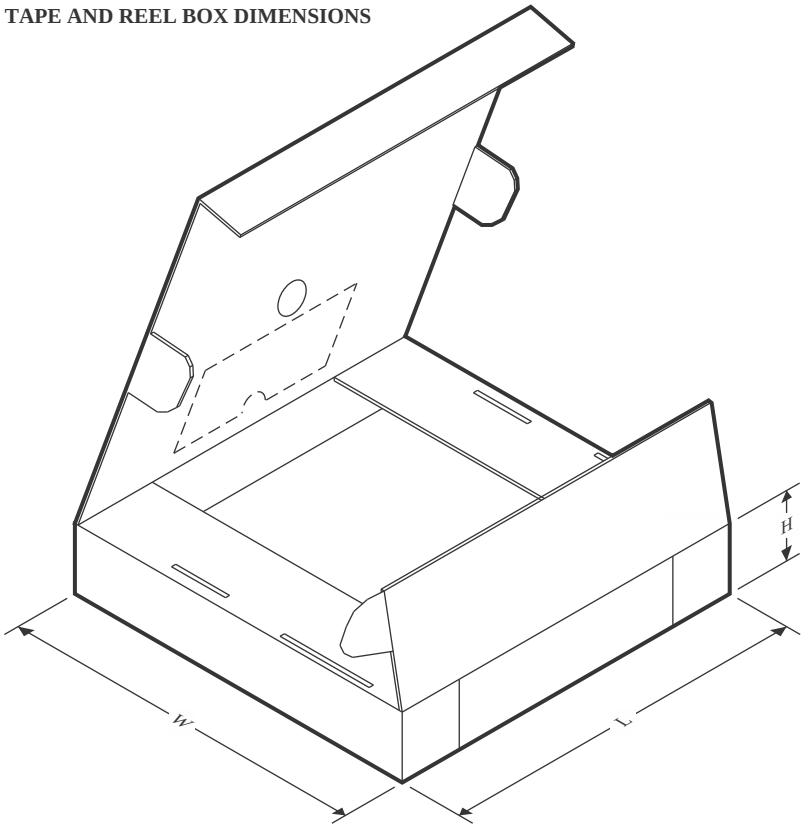
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC4538QPWRG4Q1	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HC4538QPWRQ1	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

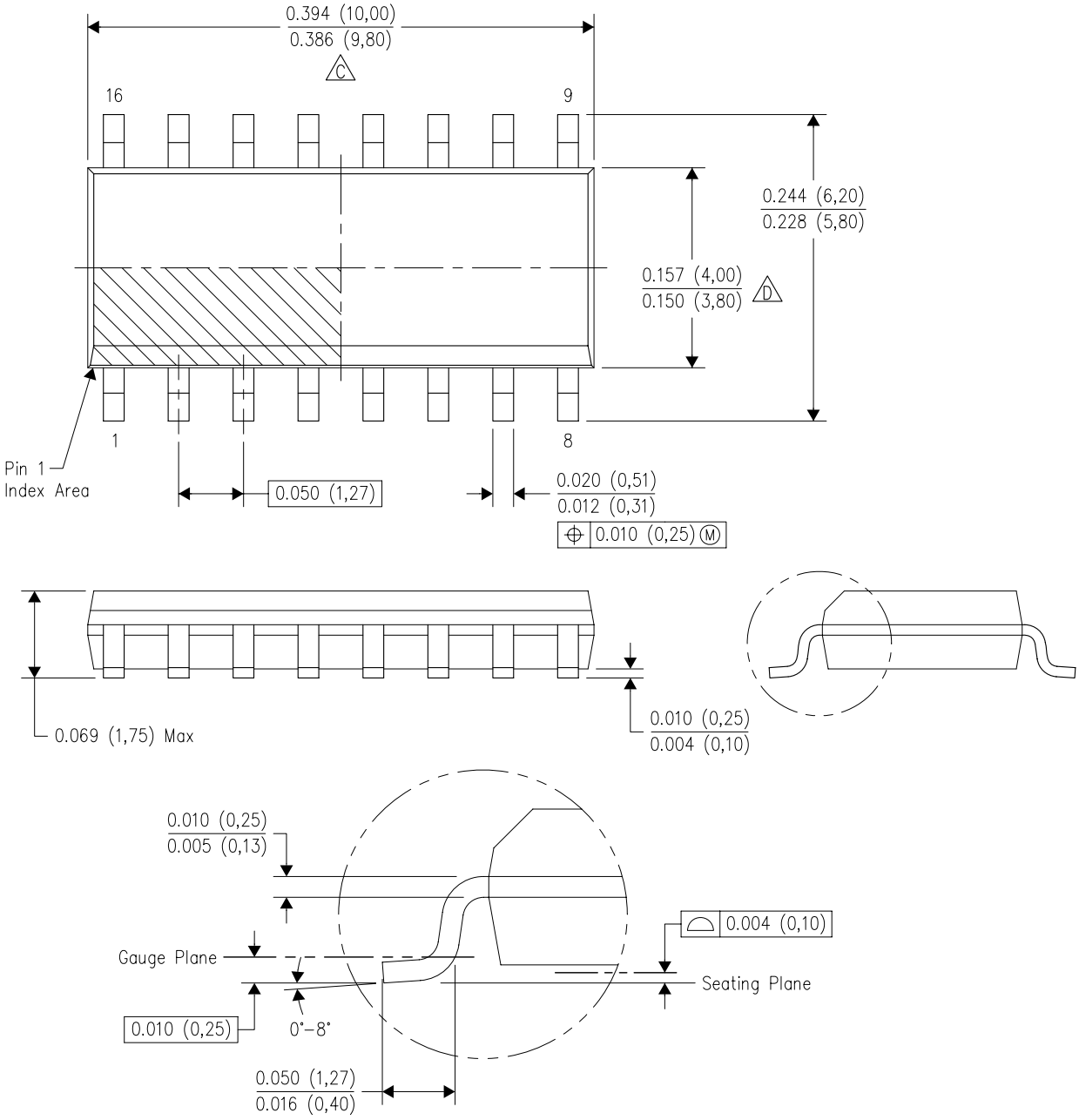
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC4538QPWRG4Q1	TSSOP	PW	16	2000	356.0	356.0	35.0
CD74HC4538QPWRQ1	TSSOP	PW	16	2000	356.0	356.0	35.0

D (R–PDSO–G16) PLASTIC SMALL OUTLINE



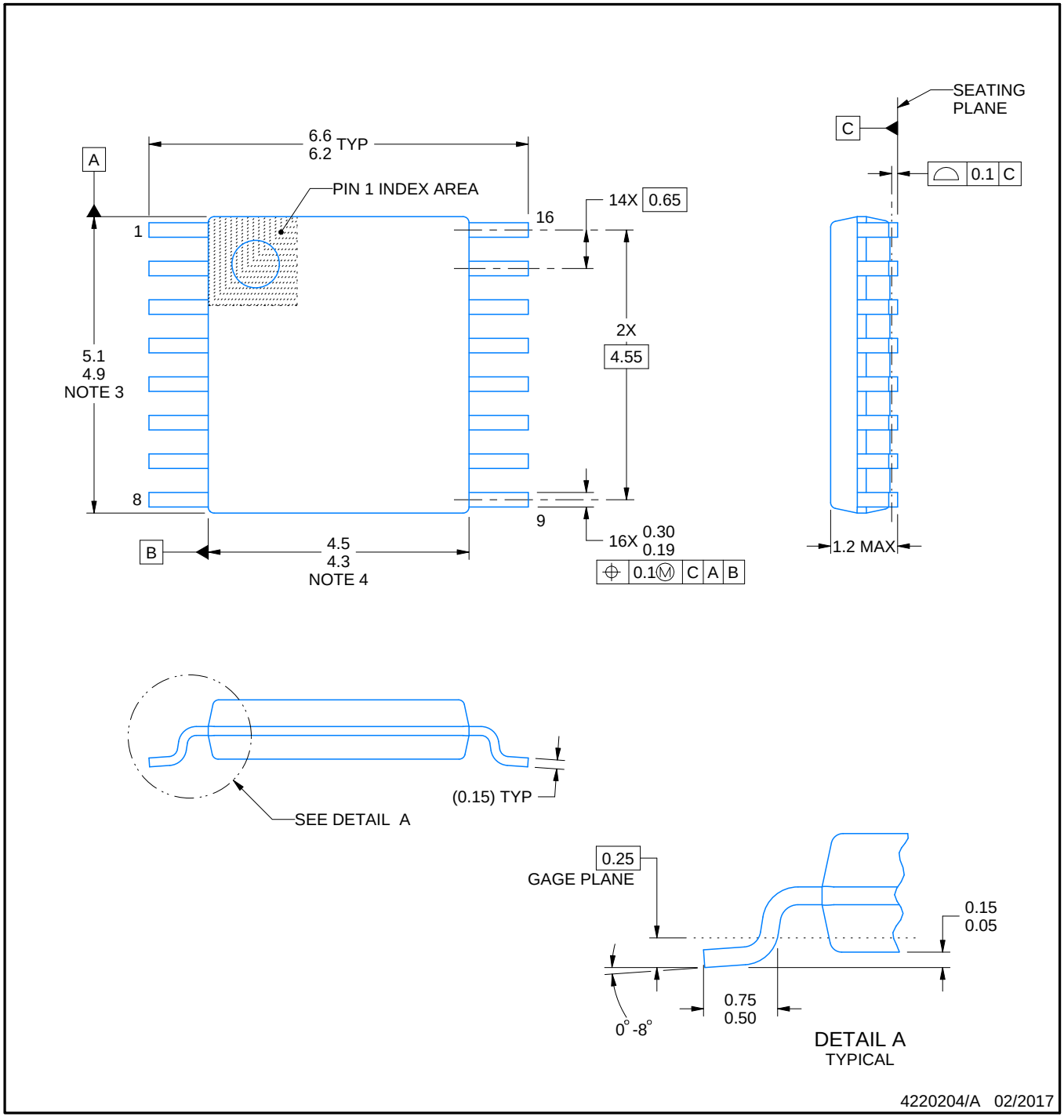
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AC.

PACKAGE OUTLINE

PW0016A

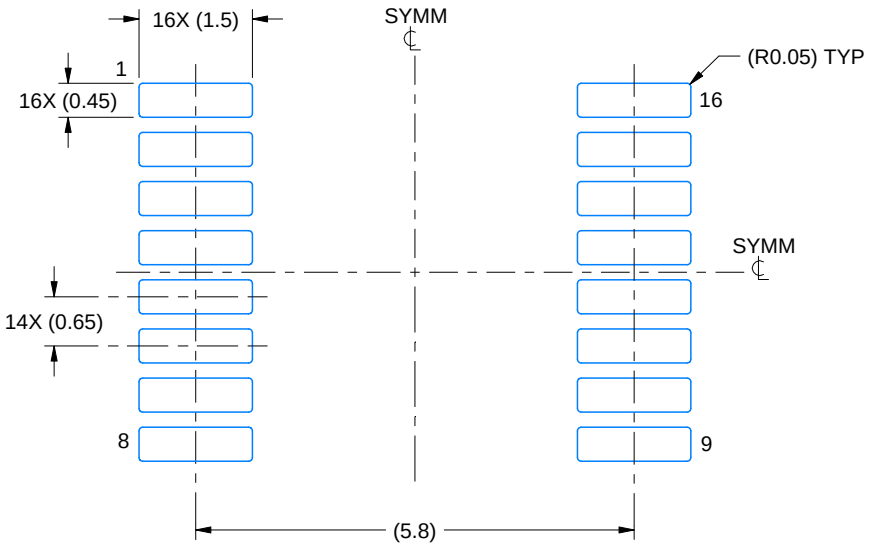
TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

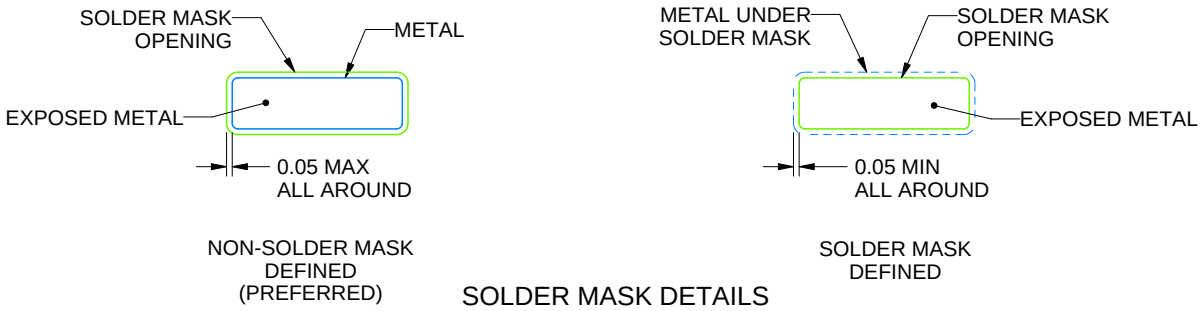


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X

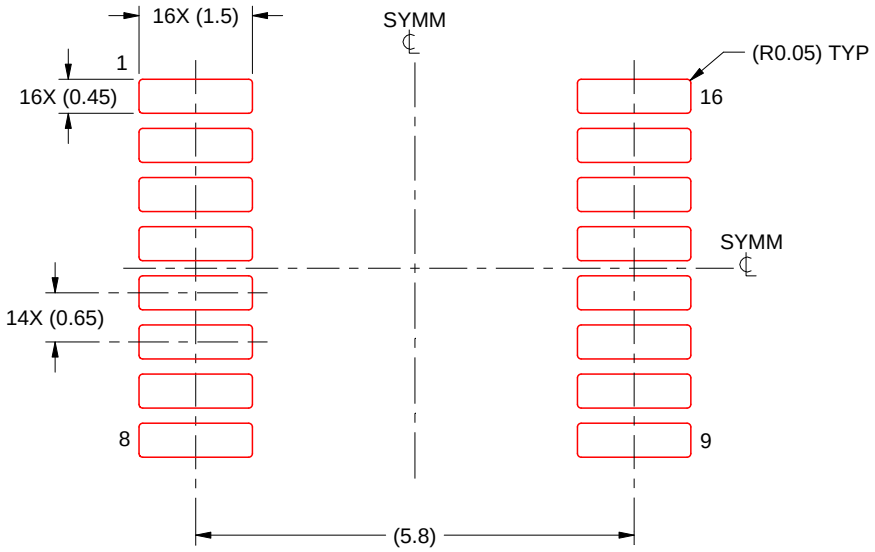


SOLDER MASK DETAILS

4220204/A 02/2017

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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